TOSHIBA Field Effect Transistor Silicon N Channel MOS Type

SSM3K124TU

High Speed Switching Applications

- 4 V drive
- Low ON-resistance: $R_{on} = 120 \text{ m}\Omega \text{ (max)} (@V_{GS} = 4V)$ $R_{on} = -83 \text{ m}\Omega \text{ (max)} (@V_{GS} = 10V)$

 $R_{on} = 83 \text{ m}\Omega \text{ (max)} (@V_{GS} = 10V)$

Absolute Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rating	Unit
Drain-source voltage		V _{DS}	30	V
Gate-source voltage		V _{GSS}	± 20	V
Drain current	DC	ID	2.4	A
	Pulse	I _{DP}	4.8	
Drain power dissipation		P _{D (Note 1)}	800	mW
		P _D (Note 2)	500	
Channel temperature		T _{ch}	150	°C
Storage temperature range		T _{stg}	-55~150	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

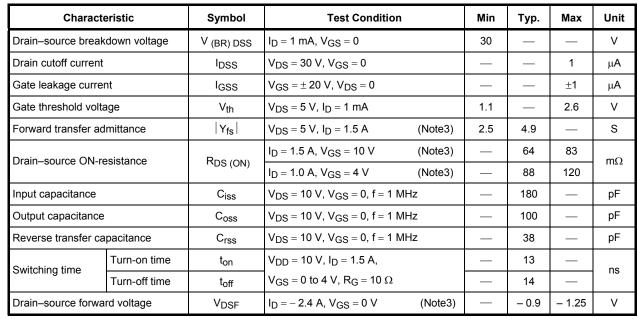
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Note 1: Mounted on a ceramic board.

(25.4 \text{ mm} \times 25.4 \text{ mm} \times 0.8 \text{ t}, \text{ Cu Pad: } 645 \text{ mm}^2)

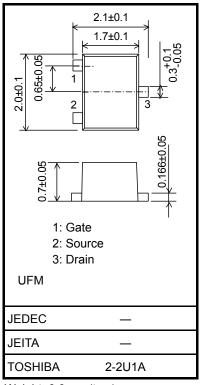
Note 2: Mounted on an FR4 board.

(25.4 \text{ mm} \times 25.4 \text{ mm} \times 1.6 \text{ t}, \text{ Cu Pad: } 645 \text{ mm}^2)
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Electrical Characteristics (Ta = 25°C)



Note3: Pulse test



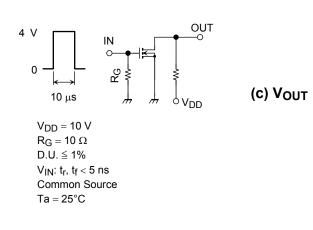
Weight: 6.6 mg (typ.)

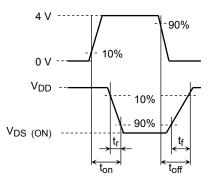
Unit: mm

Switching Time Test Circuit

(a) Test Circuit

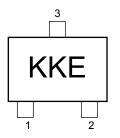
(b) V_{IN}

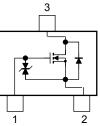




Marking

Equivalent Circuit (top view)





Precaution

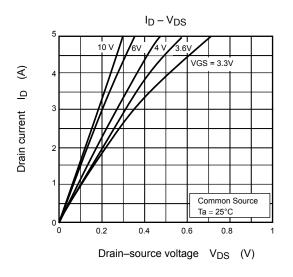
 V_{th} can be expressed as the voltage between gate and source when the low operating current value is I_D = 1 mA for this product. For normal switching operation, V_{GS} (on) requires a higher voltage than V_{th} and V_{GS} (off) requires a lower voltage than V_{th} .

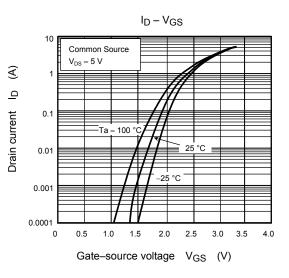
(The relationship can be established as follows: $V_{GS (off)} < V_{th} < V_{GS (on).}$) Take this into consideration when using the device.

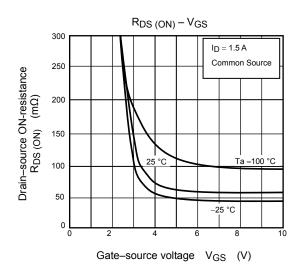
Handling Precaution

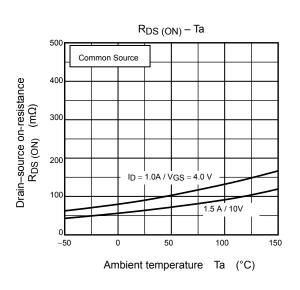
When handling individual devices that are not yet mounted on a circuit board, make sure that the environment is protected against electrostatic discharge. Operators should wear antistatic clothing, and containers and other objects that come into direct contact with devices should be made of antistatic materials.

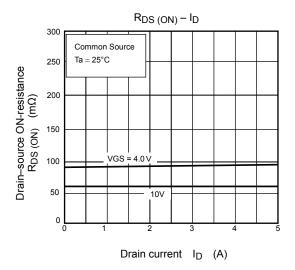
TOSHIBA

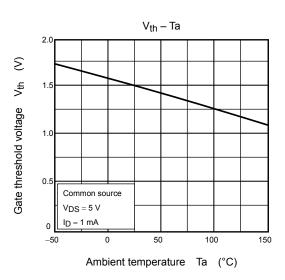




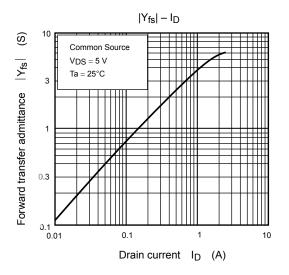


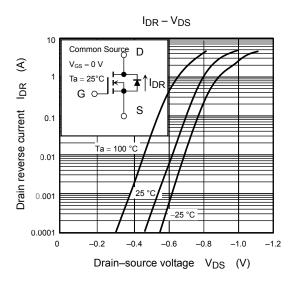


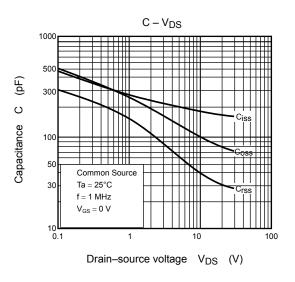


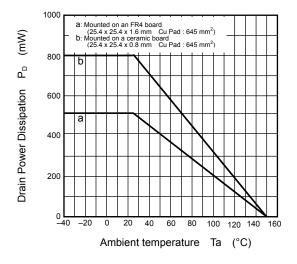


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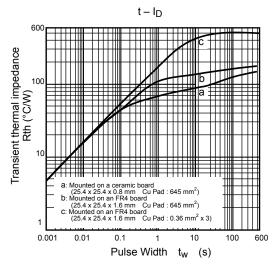








 $\mathsf{t}-\mathsf{I}_\mathsf{D}$ 600 Common Source tof V_{DD} = 10 V VGS = 0 to 4 V Switching time t (ns) Ta = 25°C 100 $R_G = 10 \Omega$ ton 1 tr 1 L 0.01 0.1 10 Drain current ID (A)



2007-11-01

RESTRICTIONS ON PRODUCT USE

20070701-EN GENERAL

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- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property.
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